



# 7P30

## POWER MOSFET

### -6A, -300V, SWITCHING P-CHANNEL POWER MOSFET

■ DESCRIPTION

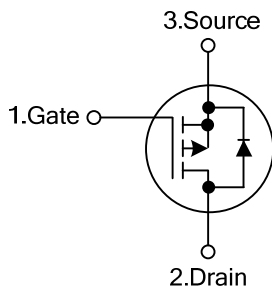
The UTC **7P30** is a P-channel MOS Field Effect Transistor. it uses UTC's advanced technology to provide the customers with high switching speed and a minimum on-state resistance.

The UTC **7P30** is suitable for high voltage switching applications.

■ FEATURES

- \*  $R_{DS(ON)} \leq 1.2\Omega @ V_{GS} = -10V, I_D = -3.0A$
- \* High switching speed
- \* Low input capacitance

■ SYMBOL



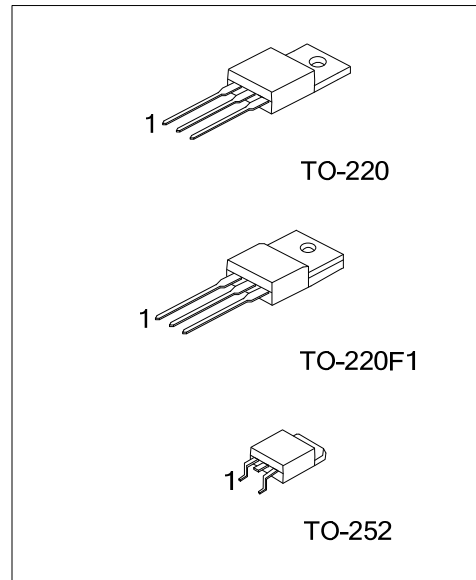
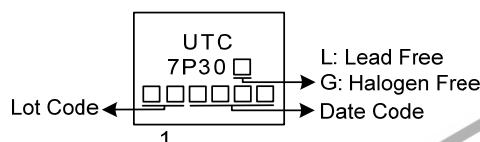
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
7P30L-TA3-T	7P30G-TA3-T	TO-220	G	D	S	Tube
7P30L-TF1-T	7P30G-TF1-T	TO-220F1	G	D	S	Tube
7P30L-TN3-R	7P30G-TN3-R	TO-252	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>7P30G-TA3-T</p> <p>(1)Packing Type</p> <p>(2)Package Type</p> <p>(3)Green Package</p>	<p>(1) T: Tube, R: Tape Reel</p> <p>(2) TA3: TO-220, TF1: TO-220F1, TN3: TO-252</p> <p>(3) G: Halogen Free and Lead Free, G: Halogen Free</p>
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■ MARKING



■ ABSOLUTE MAXIMUM RATING ( $T_A=25^\circ\text{C}$  unless otherwise specified)

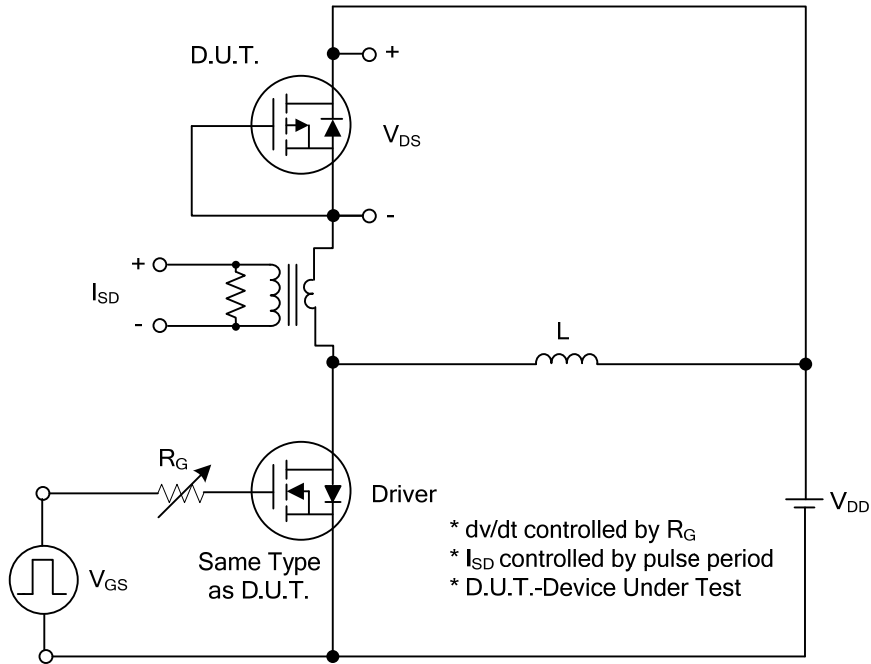
PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	-300	V
Gate-Source Voltage		$V_{GSS}$	$\pm 30$	V
Drain Current	DC	$I_{D(DC)}$	-6.0	A
	Pulsed (Note 2)	$I_{D(pulse)}$	-24	A
Single Avalanche Current (Note 3)		$I_{AS}$	-6.0	A
Single Avalanche Energy (Note 3)		$E_{AS}$	180	mJ
Power Dissipation	$T_C=25^\circ\text{C}$	TO-220	110	W
		TO-220F1	38	W
		TO-252	55	W
	$T_A=25^\circ\text{C}$	TO-220	2	W
		TO-220F1		
		TO-252	1.14	W
Channel Temperature		$T_{CH}$	+150	$^\circ\text{C}$
Storage Temperature Range		$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

- Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.  
 2.  $P_w \leq 10\mu\text{s}$ , Duty cycle  $\leq 1\%$ .  
 3. Starting  $T_{CH}=25^\circ\text{C}$ ,  $R_G=25\Omega$ ,  $V_{GS}=-20\text{V} \rightarrow 0$ .

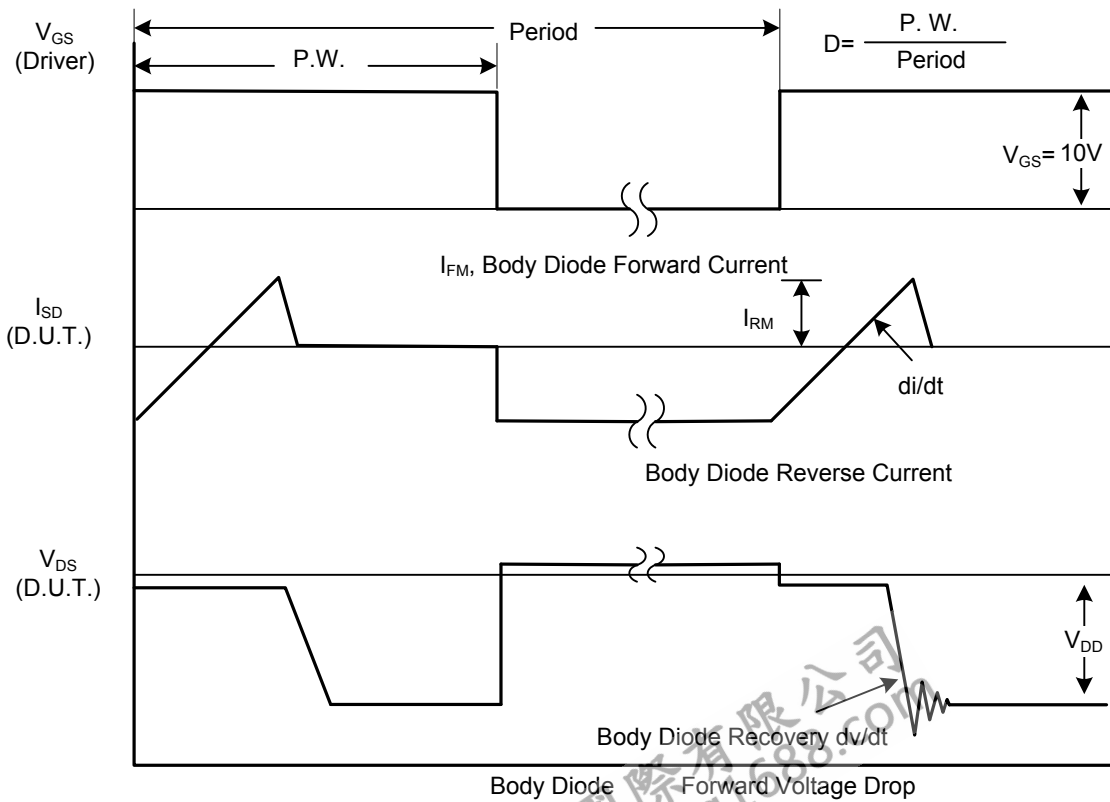
■ ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$  unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS}=-300\text{V}$ , $V_{GS}=0\text{V}$			-1.0	$\mu\text{A}$
Gate-Source Leakage Current	Forward	$I_{GSS}$	$V_{GS}=+30\text{V}$ , $V_{DS}=0\text{V}$		+100	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$ , $I_D=-250\mu\text{A}$	-2.0		-4.5	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=-10\text{V}$ , $I_D=-3.0\text{A}$			1.2	$\Omega$
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	$C_{ISS}$	$V_{GS}=0\text{V}$ , $V_{DS}=-10\text{V}$ , $f=1.0\text{MHz}$		1040		pF
Output Capacitance	$C_{OSS}$			360		pF
Reverse Transfer Capacitance	$C_{RSS}$			70		pF
<b>SWITCHING PARAMETERS</b>						
Total Gate Charge	$Q_G$	$V_{GS}=-10\text{V}$ , $V_{DD}=-200\text{V}$ , $I_D=-6.0\text{A}$		23.1		nC
Gate to Source Charge	$Q_{GS}$			7.1		nC
Gate to Drain Charge	$Q_{GD}$			12.9		nC
Turn-ON Delay Time	$t_{D(ON)}$	$V_{DD}=-125\text{V}$ , $V_{GS(ON)}=-10\text{V}$ , $I_D=-3.0\text{A}$ , $R_G=10\Omega$ , $R_L=42\Omega$		24		ns
Rise Time	$t_R$			16		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			47		ns
Fall-Time	$t_F$			14		ns
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Diode Forward Voltage	$V_{SD}$	$I_F=-6.0\text{A}$ , $V_{GS}=0\text{V}$		3.4		V
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F=-6.0\text{A}$ , $V_{GS}=0\text{V}$ , $di/dt=50\text{A}/\mu\text{s}$		155		ns
Body Diode Reverse Recovery Charge	$Q_{rr}$			930		nC

■ TEST CIRCUITS AND WAVEFORMS

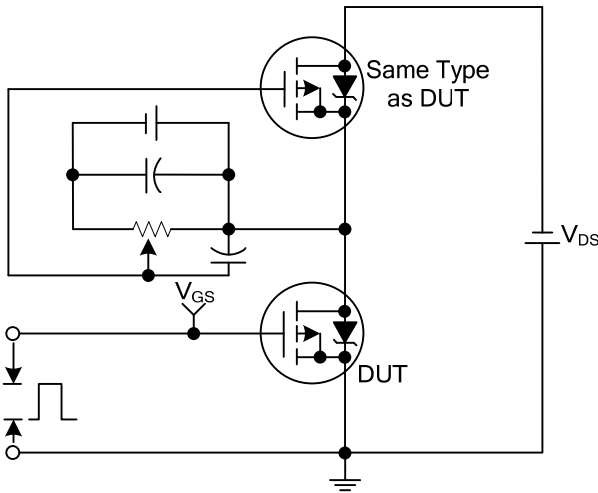


Peak Diode Recovery  $dv/dt$  Test Circuit

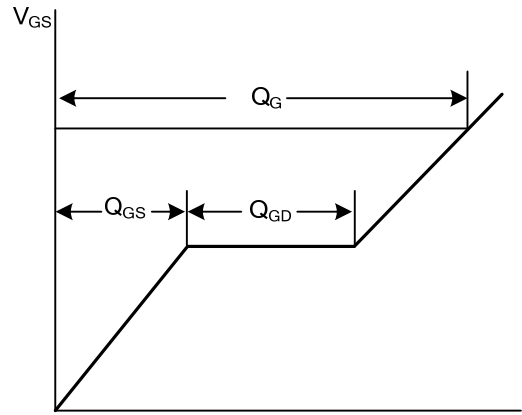


Peak Diode Recovery  $dv/dt$  Waveforms

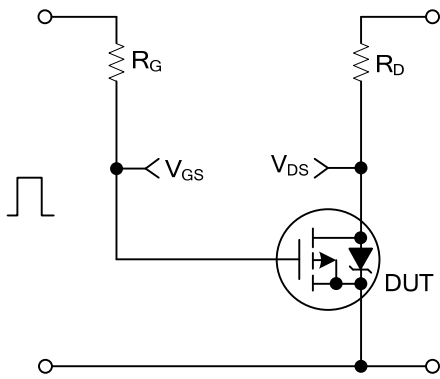
■ TEST CIRCUITS AND WAVEFORMS



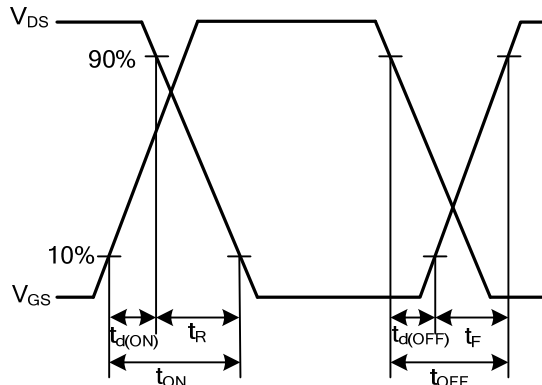
Gate Charge Test Circuit



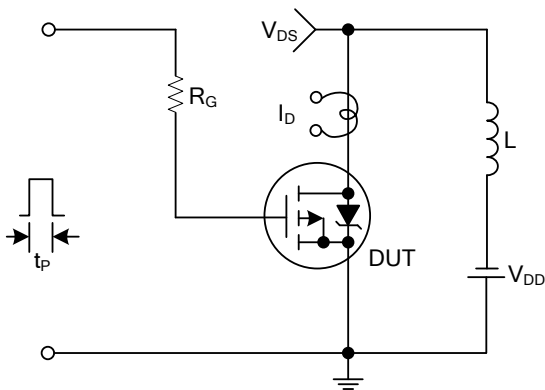
Gate Charge Waveforms



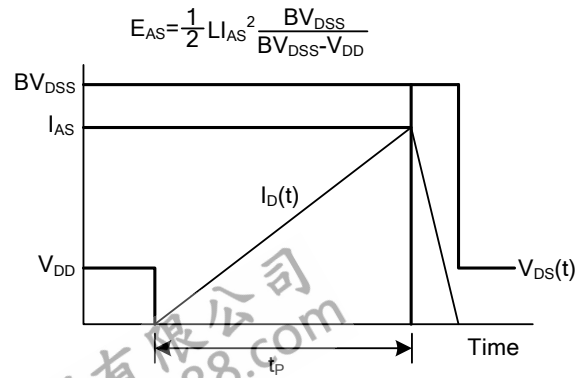
Resistive Switching Test Circuit



Resistive Switching Waveforms

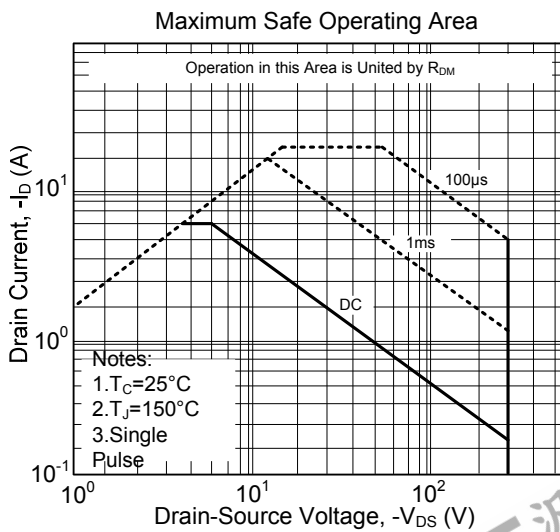
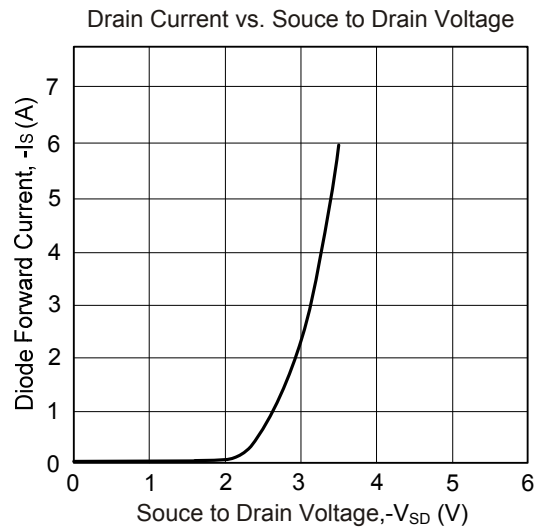
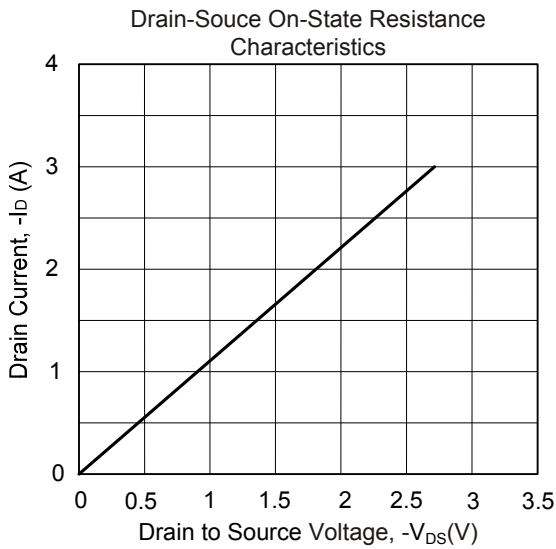
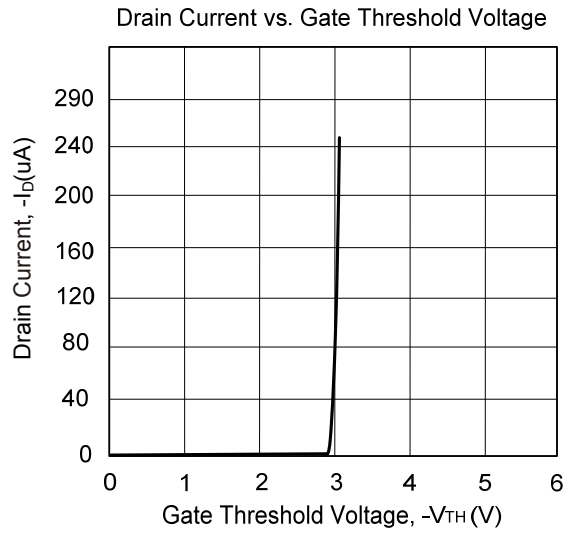
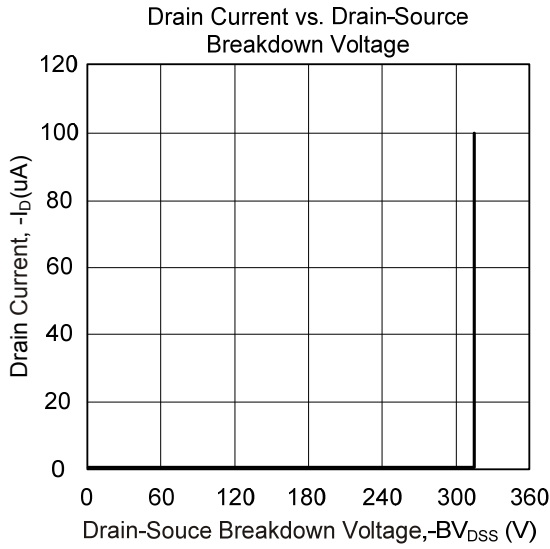


Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

■ TYPICAL CHARACTERISTICS



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